## NSN 5962-01-382-6317

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Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Next assembly: 8506200-91
Features Provided:
Programmed and tested to mil-std-883
Inclosure Configuration:
Leadless flat pack
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Case Outline Source And Designator:
C-4 mil-m-38510
Product Name:
2k x 8 registered prom
Voltage Rating And Type Per Characteristic:
4.5 volts applied and 5.5 volts applied
Memory Device Type:
Prom
Hybrid Technology Type:
Monolithic
Special Features:
One time programmable
Test Data Document:
81349-mil-m-38510 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quantity:
28 leadless
Specification Data:
67268-5962-88735033a government standard
Departure From Cited Designator:
Prograamed per: (07187)tt8514393-100
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli

Fiig:

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